Oxidation layering mechanism of graphene-like MoS₂ prepared by the intercalation-detonation method

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ABSTRACT

Graphene-like MoS₂ has attracted significant interest because of its unique electronic, optical, and catalytic properties with two-dimensional lamellar structure. Three kinds of intercalated MoS₂ samples were prepared using different oxidation layering methods, which are the first steps of intercalation-detonation. The oxidation layering mechanism of graphene-like MoS_2 was systematically characterized using Fourier transform infrared, X-ray photoelectron, and Raman spectroscopy techniques. The bulk MoS₂ sample was gradually oxidized from the edge to the interlayer in the presence of concentrated H₂SO₄ and KMnO₄. A large number of hydroxyl groups were bonded to the sulfur atom layer, forming S-OH bonds in the basal planes of the MoS₂ structure. The addition of deionized water to concentrated H₂SO₄ generated a large amount of heat, promoting the generation of more S-OH bonds, destroying residual Van der Waals forces between the layers, and finally stripping off parts of the flakes. The continuous addition of deionized water in the high temperature stage resulted in the largest oxidative intercalation effect. Additionally, the η factor was determined to compare the intensities of B_{1u} and A_{1g} peaks in the Raman spectra and quantify the effect of oxidative intercalation. The highest value of η was obtained when deionized water was added continuously during the preparation of intercalated MoS₂.

1 Introduction

Layered materials have recently attracted considerable Address correspondence to huping1985@126.com attention because of their exotic electronic properties and high specific surface area, which are important for sensing, catalysis, and energy storage applications.

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Graphene is one of the most well known layered materials; transition metal dichalcogenides (TMDs), transition metal oxides, and other two-dimensional (2D) compounds are also widely used [1]. Molybdenum disulfide (MoS₂) is one of the most studied TMDs because of its superior optical and electronic properties [2]. In the bulk form, MoS_2 has a layered structure with strong covalent bonding in each layer and weak Van der Waals bonding between the layers. Each layer has a thickness of 6.5 Å. The S-Mo-S bonds form a sandwich structure of MoS₂ wherein two hexagonal planes of S atoms are separated by a plane of Mo atoms [3, 4]. Unlike graphene which is an excellent conductor, bulk crystalline MoS₂ is a semiconductor with an indirect band gap of approximately 1.2 eV, which gradually increases with decrease in the number of layers. Atomically layered graphene-like MoS₂ is a semiconductor material with a direct band gap, and the band gap of single-layer MoS_2 is 1.9 eV [5–7].

Owing to the adjustable band gap, graphene-like MoS₂ has significant potential for applications in photoelectronic devices. However, it is difficult to obtain high-purity graphene-like MoS₂ structures using conventional methods, such as micromechanical exfoliation, Li⁺ intercalation, liquid ultrasonic, and chemical vapor deposition [8–12]. Furthermore, other factors, such as small-scale preparation, poor repeatability, time consumption, low efficiency, and product quality hinder the development of this attractive material. Thus, reproducible production of graphene-like nanosheets in bulk quantities is still a challenge. With the rapid development of various ultrathin MoS₂-based devices, unique properties characterization and easy identification methods have emerged. Raman spectroscopy, X-ray photoelectron spectroscopy (XPS), high-resolution transmission electron microscopy, scanning tunneling microscopy, and other advanced techniques have been used to characterize this promising layered material. For decades, Raman spectroscopy has been used to study the different crystalline structures of MoS₂, and various phonons vibration modes have been identified. For example, Chen et al. [13] observed the longitudinal acoustic phonons at the M point (LA(M)) at approximately 460 cm⁻¹ in 1974. The in-plane E_{2g}^1 and the out-of-plane A1g vibration modes were observed by Bertrand et al. [14] in 1992. Recently, Lee et al. [15]

and Li et al. [16] reported two opposite points of view regarding the E_{2g}^1 and the A_{1g} vibration modes. According to Lee et al., the frequencies, intensities, and widths of the E_{2g}^1 and the A_{1g} peaks depend on the layer thickness of ultrathin MoS₂ flakes. Whereas, Li et al. proposed that the Raman frequencies of the E_{2g}^1 and A_{1g} peaks vary monotonously with the number of layers in ultrathin MoS₂ flakes and can be used as reliable features to identify the number of layers. Furthermore, other lesser-known second order modes, such as Raman-inactive E_{1u}^2 and B_{1u} , have been observed by resonance Raman spectroscopy [17].

A novel intercalation-detonation method to prepare graphene-like MoS₂ was reported in our previous study [18], wherein for the first time, oxygen-containing groups were used as intercalation compounds of layered structures and explosion technology was used to exfoliate the intercalated MoS₂.

In this paper, we systematically studied the oxidation layering mechanism of graphene-like MoS_2 by Fourier transform infrared spectroscopy, XPS, and Raman spectroscopy. In order to validate the proposed mechanism, three kinds of intercalated MoS_2 samples were prepared using different oxidation layering methods by varying the method of addition of water. Most importantly, we determined the factor η , which is the ratio of the intensities of B_{1u} and A_{1g} peaks in the Raman spectrum, to quantify the extent of oxidative intercalation.

2 Experimental

2.1 Intercalation process

Pure analytical grade MoS₂ powder, NaNO₃, and KMnO₄ were used as the raw materials, and 98% concentrated sulfuric acid was used to oxidize bulk MoS₂. Three kinds of preparation methods were used to study the intercalation mechanism of MoS₂.

The typical procedure used for the preparation of intercalated MoS₂ is described as follows. The MoS₂ powder and the NaNO₃ crystals were dissolved in a certain volume of 98% concentrated sulfuric acid in the mass ratio of 2:1; the concentration of MoS₂ powder dispersed in concentrated sulfuric acid was 0.25 g/mL. The reaction flask was placed in an ice

bath with violent stirring, and a certain quantity of $KMnO_4$ (three times the mass of MoS_2 powder) was added slowly to avoid a sudden increase in the temperature. After a reaction time of 120 min, the flask was heated to 35 °C for 60 min and then maintained at 90 °C for 5 min. The reactive solution was diluted during stirring, and a certain amount of warm deionized water was added slowly during the heating-up process from 35 to 90 °C. A 5% hydrogen peroxide solution was added to the solution after the heating process to remove the KMnO₄. Subsequently, the solution was vacuum filtered and thoroughly washed with deionized water until the pH of the filtrate became neutral. Intercalated MoS_2 was obtained after the filtration.

Three different methods of addition of deionized water were used to prepare the intercalated MoS_2 flakes. In method 1, deionized water of the same volume as sulfuric acid was added to the solution during the reaction at 35 °C. In method 2, deionized water was continuously added to the solution during the heating-up process from 35 to 90 °C. In method 3, deionized water was added to the solution during the heating-up process from 35 to 90 °C and during the heating-up process from 35 to 90 °C and during the heating-up process from 35 to 90 °C and during the heating-up process from 35 to 90 °C and during the holding step at 90 °C.

2.2 Spectroscopic analyses

Raman spectroscopy (Jobin Yvon HR-800) was performed using a HeNe laser with an excitation wavelength of 632.8 nm. The XPS (PHI-5400) measurements were performed using monochromatic aluminum KR X-rays. The Thermo Scientific[™] Advantage software was used for the XPS data analyses. The FT-IR measurements (Nicolet iN10 MX) were performed using the KBr tablet method in the scan range of 400–4,000 cm⁻¹.

3 Results and discussion

3.1 FT-IR spectra of the intercalated MoS₂ samples

Figure 1 shows the FT-IR spectra of the intercalated MoS₂ samples prepared using the three different methods along with that of bulk MoS₂. High-intensity peaks at approximately 1,640 and 3,400 cm⁻¹ were observed in both the bulk and the intercalated MoS₂



Figure 1 FT-IR spectra of the bulk and the intercalated MoS_2 samples.

samples, and the intensity of the peaks increased from the bulk to the intercalated MoS_2 . The peaks at 1,640 cm⁻¹ and 3,000–3,800 cm⁻¹ correspond to water bending and hydroxyl stretching vibration modes, respectively. These results indicate that a small amount of water exists in the bulk MoS_2 sample, while a higher amount of water and hydroxyl groups exist in the intercalated MoS_2 samples. In addition, a peak at approximately 1,100 cm⁻¹ was observed in all the intercalated MoS_2 samples except the bulk MoS_2 sample, and the intensity of this peak increased from methods 1 to 3. The peak at 1,030–1,400 cm⁻¹ denotes the S=O stretching vibration. Therefore, the effect of oxidative intercalation increases from methods 1 to 3.

3.2 XPS spectra of the intercalated MoS₂ samples

The XPS measurements were carried out to characterize the chemical compositions of the bulk and the intercalated MoS_2 samples, and the results are shown in Fig. 2. The high-resolution Mo 3d and S 2p spectra showed peaks corresponding to the Mo 3d3/2, Mo 3d5/2, S 2p1/2, and S 2p3/2 components of MoS_2 , respectively (Figs. 2(a) and 2(b)) [19].

The high-resolution O 1s spectrum of the bulk MoS_2 sample, as shown in Fig. 2(c) shows a peak at 532.1 eV, which is associated with the hydroxyl group formed by dissociation of water. The O 1s spectrum of the intercalated MoS_2 samples shows a peak at 533 eV, which is related to the S–OH bond [20]. This indicates that the oxygen-containing functional groups were bonded to the surface or the sulfur atom layer of MoS_2



Figure 2 XPS spectra of the bulk and the intercalated MoS_2 samples. (a) High-resolution Mo 3d spectra, (b) high-resolution S 2p spectra, and (c) high-resolution O 1s spectra.

during the three different intercalation processes. The weak peak observed at 531.9 eV in the intercalated MoS_2 sample prepared using method 3, is related to rudimental dissociation of water. Additionally, the intensity of the peak at 533 eV increased from methods 1 to 3, which indicates that the amount of S–OH bonds and the effect of oxidative intercalation increased from methods 1 to 3.

3.3 Raman spectra of intercalated MoS₂ samples

Raman spectroscopy was used to characterize the vibration frequencies of the atoms of the bulk and the intercalated MoS_2 samples, and the results are shown in Fig. 3. The MoS_2 samples showed peaks at approximately 383 and 405 cm⁻¹ corresponding to the vibration modes of E_{2g}^1 and A_{1g} , respectively, consistent with previously reported results [1]. Besides, a peak



Figure 3 Raman spectra of the bulk and the intercalated MoS_2 samples.

near the A_{1g} mode at approximately 415 cm⁻¹ was observed in the Raman spectra of the bulk and the intercalated MoS₂ samples. This peak corresponds to the vibrational B_{1u} mode and is consistent with that reported in the literature [16]. The intensity ratio of B_{1u} and A_{1g} peaks was calculated to be 0.61, 0.68, 0.87, and 1.15 for the bulk MoS_2 and the intercalated MoS_2 samples prepared using methods 1 to 3, respectively. Combining the results of FT-IR spectroscopy and XPS, it can be confirmed that the effect of oxidative intercalation increases from methods 1 to 3. In addition, the intensity ratio of B_{1u} and A_{1g} peaks in the Raman spectra increased from methods 1 to 3. This is attributed to the effect of oxidative intercalation, in which oxygen-containing groups are inserted into the MoS₂ layer, and the spacing between the layers is increased. This change in the layer structure induces the evolution of the vibrational mode at 415 cm⁻¹, and the intensity ratio of B_{1u} and A_{1g} peaks corresponds to the degree of oxidative intercalation.

The B_{1u} vibration mode originates from the shoulder of the A_{1g} peak in bulk MoS_2 , which evolves into a separate peak at 415 cm⁻¹ with the variety of MoS_2 layers. Previous literature [17] reports that the peak at 415 cm⁻¹ originates from the B_{1u} Raman-inactive mode because of a two-phonon scattering process involving longitudinal quasi-acoustic phonons and transverse optical phonons. We define the intensity ratio of B_{1u} and A_{1g} peaks as a factor η , which represents the layer spacing and the amount of bonds in the MoS_2 flakes that causes a change in the intensity ratio η is expressed as

$$\eta = \frac{I_{\rm B1u}}{I_{\rm A1g}} \tag{1}$$

where I_{B1u} is the intensity of the B_{1u} peak and I_{A1g} is the intensity of the A_{1g} peak. Thus, the intercalated sample obtained using method 3 exhibits the highest value of η , and consequently, the best oxidative intercalation effect.

3.4 Mechanism of oxidative intercalation

The results of the present study show that the effect of oxidative intercalation increased from methods 1 to 3. The difference between methods 1 to 3 is the method of addition of deionized water. The deionized water was added to the solution during the reaction at 35 °C in method 1, it was continuously added to the solution during the heating-up process from 35 to 90 °C in method 2, and it was added to the solution during the heating-up process from 35 to 90 °C and during the heating-up at 90 °C in method 3.

The proposed mechanism of oxidative intercalation of bulk MoS_2 is shown in Fig. 4. In the low-temperature stage, the strong oxidants concentrated H_2SO_4 and $KMnO_4$ were adsorbed on the MoS_2 edges, and the edges were oxidized and intercalated by the generated hydroxyl and other oxygen-containing groups. The oxygen-containing groups reduced the intermolecular force between the layers at the edges and increased the layer spacing of the MoS_2 flakes.

In the mid-temperature stage, with the rise in the

reaction temperature, the oxidation effect of concentrated H_2SO_4 and KMnO₄ gradually increased, resulting in the generation of more oxygen-containing groups between the MoS_2 layers. With further increase in the lamellar spacing, the oxidant gradually penetrated to the inner layer.

In the high-temperature stage, the oxidation effect of concentrated H₂SO₄ further increased because of the high reaction temperature, causing more hydroxyl groups bonded to the sulfur atom layer to form S–OH bonds in the basal planes of the MoS₂ structure. On the other hand, the dilution of concentrated H₂SO₄ with deionized water in methods 2 and 3 was exothermic, which promoted the generation of S–OH bonds, destroyed the residual Van der Waals forces between the layers, and finally stripped off parts of the flakes. Furthermore, the addition of deionized water also reduced the temperature of the concentrated H₂SO₄ core during the holding step at 90 °C in method 3, preventing oxidative damage of the MoS₂ layered structure.

Finally, the bulk MoS_2 was oxidized and intercalated. Parts of the oxidation-intercalated MoS_2 flakes were stripped off, forming graphene-like MoS_2 . Other largesized MoS_2 flakes are waiting to be exfoliated by subsequent exfoliation process.

4 Conclusion

In summary, we systematically investigated the



Figure 4 Schematic illustration of the oxidation layering mechanism.

oxidation layering mechanism of graphene-like MoS₂ by using FT-IR, XPS, and Raman spectroscopy techniques. In order to validate the proposed mechanism, three kinds of intercalated MoS₂ samples were prepared using different oxidation layering methods by varying the method of addition of water. The FT-IR spectroscopy and the XPS results showed that the method of addition of deionized water significantly affected the degree of oxidative intercalation of the MoS₂ samples. The bulk MoS₂ sample was gradually oxidized from the edge to the interlayer by the addition of concentrated H₂SO₄ and KMnO₄, and a large amount of hydroxyl groups were bonded to the sulfur atom layer, forming S-OH bonds in the basal planes of the MoS₂ structure. The addition of deionized water to concentrated H₂SO₄, which was exothermic, promoted the formation of more S-OH bonds, destroyed the residual Van der Waals forces between the layers, and finally stripped off parts of the flakes. Most importantly, the intensity ratio of B_{1u} and A_{1g} peaks in the Raman spectra, η , was determined to quantify the effect of oxidative intercalation. The highest value of η was obtained for the method in which deionized water was added continuously during the preparation of intercalated MoS₂.

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